## **SECTION A (40 MARKS)**

Answer ALL the questions in this section in the spaces provided.

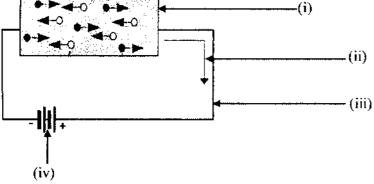
(i)	electromotive force;	(2 marks)
(ii)	current.	(2 marks)
Deter	rmine the colour code in each case of the following resistors.	
(i) 	$2.4 \times 10^7 \Omega 10\%$ .	(2 marks)
(ii)	5.3 x 10 <sup>10</sup> Ω 5%.	(2 marks)
		(2 marks)
(a)	Explain one limitation of excess-3 code as used in computers.	(2 marks)
(b)	Convert 24,900 mΩ to ohms.	(2 marks)

(i) 	65À <sub>8</sub> ;	(1 mark
(ii)	12316.	(1 mark
(iii)	1004 <sub>8</sub> ;	(1 mark
(iv)	AF9 <sub>16</sub> .	(1 mark
 Evalu (i)	nate each of the following binary arithmetic. Show your working	(2 marks
		(2 marks
(ii)		•

	·
Outline two types of resistors used in basic electronics.	(2 mark
	(4 marks
	F
o's complement, determine 1000 0011 <sub>2</sub> - 1010 1111 <sub>2</sub> .	(4 marks
	two methods of BCD subtraction.

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9. Figure 1 shows the outline of current in a semiconductor material. Identify the parts labelled (i), (ii), (iii) and (iy) (4 marks)



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With the aid of a diagram in	each case, outline the	e structure of each of	the following logic gates:

10.

(i)	NOR;		(2 marks
(ii)	XOR.	V	(2 marks

SECTION B (60 MARKS)

Answer any FOUR questions in this section in the spaces provided.

(a)	(i)	Explain two risks of using secondary storage media in computers.	(4 marks
	(ii)	Differentiate between optical memory and magnetic tapes as used in co	mputers. (4 marks
(b)	(i)	Determine the excess-3 equivalent of the hexadecimal number 7AD.	(3 marks)
			-
	(ii)	A potential difference of 10 V is connected to a uniform resistance wire	of length 3
		meters and a cross sectional area of 0.09 m <sup>2</sup> with 0.01 A of current flow wire. Determine the resistivity of the material.	ving in the (4 marks)

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(a)	(i)	i) Comment on the conductivity and resistivity of each of the following		
		I. metal;	(I ma	
		II. glass;	(1 mar	
		III. semiconductor.	(1 mar	
	(ii)	Explain two characteristics of an extrinsic semiconductor.	(4 mark	
(b)	(i)	Convert each of the following numbers to BCD.		
-		I. 11111010 <sub>2</sub> ;	(2 mar)	
	·			
	<del></del>	II. 10000100 <sub>2</sub> .	() mar	

7

(ii) Figure 2 shows an arrangement of logical gates. Use it to answer the question that follows.

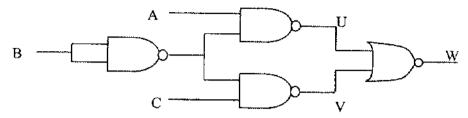


Figure 2

	Construct a truth table showing the outputs U, V and W.	(5 marks
12		
		7
(a) (i)	Perform each of the following BCD arithmetic:	
	$I. \qquad 111011010 + 1100101;$	(2 marks
<del></del>		
A1		
	II. 10101100 + 10000001.	(2 marks)
		· · · · · · · · · · · · · · · · · · ·
~		
	79.79 19.69	

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(ii) Figure 3 shows three capacitors with capacitance  $C_1$  (4  $\mu$  F),  $C_2$  (12  $\mu$  F), and  $C_3$  (24  $\mu$  F) connected across a 480V d.c supply. Use it to answer the question that follows.

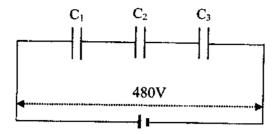


Figure 3

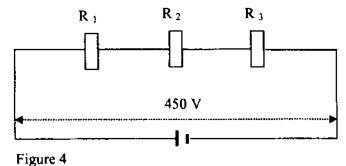
Determine the:

_		I.	total capacitance in farads (F);	(2 marks
		<del></del>		
	·			
		II.	p.d across capacitors C <sub>1</sub> and C <sub>3</sub> .	/2 monks
				(3 marks
		· · · · · · · · · · · · · · · · · · ·		
<u>-</u>				
	· <del></del> -	· <del></del>		
<del>-</del> · · ·				
(b)	Determ	ine th	e following binary arithmetic operations giving	your answer in hexadecimal.
	(i)		1011 + 1000 1101;	(3 marks)
	<del>_</del> -	<del>,</del> .,	<u> </u>	
	<del></del>	<del></del>		

		(ii)	1110 1111 – 1111 1001;	(3 marks)
14.	(a)	(i)	Outline three opportunities created by emerging trends of electronics co	omponents. (3 marks)
		(ii)	Differentiate between forward bias and reverse bias junction diodes.	(4 marks)
-	(b)	(i)	Using laws of Boolean algebra, evaluate the function:	
		·	∑m (1, 3, 5, 7, 9, 11, 13, 15).	(5 marks)

	(ii)	Using the k-map, simplify the Boolean expression:	
		$\overrightarrow{ABCD} + \overrightarrow{ABCD} + \overrightarrow{ABCD} + \overrightarrow{ABCD} + \overrightarrow{ABCD} + \overrightarrow{ABCD}$ .	(3 marks)
			- ,,
	<u>-</u>		
	<del>.</del>		
<del>_</del>			
(a)	(i)	Outline three characteristics of an electron.	(3 marks)
· <del>-</del>	<u> </u>		
	_ <del></del>		

(ii) Figure 4 shows a simple electric circuit with three resistor of R  $_1$  (50  $\Omega$ ), R  $_2$  (40  $\Omega$ ) and R  $_3$  (60  $\Omega$ ) and voltage of 450 V. Use it to answer the questions that follow.



Determine the:

I. total resistance; (2 marks)

15.

		П.	current across the resistors.	(2 marks
				<del></del>
(b)	(i)	(i) With the aid of a diagram, outline the structure of a computer magnetic disk.		
	,	Show	ing the track and sectors.	(3 marks)
				······
		- <del></del> .		
	(ii)	switch	er tap is controlled by three switches. The warm water flows ites $X$ , $Y$ and $Z$ are in the same position. When $X$ and $Y$ are items, warm water flows on condition that switch $Z$ is low.	whenever n different
			a truth table to represent this information.	(5 marks)
				· · · · · · · · · · · · · · · · · · ·
				·
				····· <u></u>
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